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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Application Number	10/708,222
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		First Named Inventor	Ming-Dou Ker
		Group Art Unit	2816
		Examiner Name	Zweizig
		Attorney Docket Number	SISP0009USA
Sheet	1	of	1

OTHER PRIOR ART -- NON PATENT LITERATURE DOCUMENTS			
Examiner Initials ¹	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²
JZ	1	H. NEUTÉBOOM, B.M. J. KUP, M. JANSSENS; A DSP-based hearing instrument IC; IEEE Journal of Solid-State Circuits, Nov. 1997; page 1790 - page 1806; VOL. 32.	
JZ	2	H. BANBA, H. SHIGA, A. UMEZAWA, T. MIYABA, T. TANZAWA, S. ATSUMI, K. SAKUI; A CMOS bandgap reference circuit with sub-1-V operation; IEEE Journal of Solid-State Circuits; May 1999; page 670 - page 674; VOL. 34	
JZ	3	G. GIUSTOLISI; A Low-Voltage Low-Power Voltage Reference Based on Subthreshold MOSFETs; IEEE Journal of Solid-State Circuits; Jan. 2003, page 151 - page 154; VOL.38, No.1	
JZ	4	P. MALCOVATI, F. MALOBERTI, M. PRUZZI, C. FIOCCHI; Curvature compensated BICMOS bandgap with 1-V supply voltage; IEEE Journal of Solid-State Circuits; July 2001; page 52 - page 55; VOL.38, No.7	
JZ	5	YUEMING JIANG, EDWARD K.F. LEE; A 1.2 V bandgap reference based on transimpedance amplifier; ISCAS 2000-IEEE international symposium on Circuits and Systems; May 23-31, 2000; page 261 - page 264	
JZ	6	SHU-YUAN CHIN, CHUNG-YU WU, A New Type of Curvature-Compensated CMOS Bandgap Voltage Reference; VLSITSA; 1991; page 398 - page 402	
JZ	7	KA NANG LEUNG, IEEE, PHILIP K. T. MOK; A Sub-1-V 15-ppm/C CMOS Bandgap Voltage Reference without Requiring Low Threshold Voltage Device; IEEE Journal of Solid-State Circuits; April 2002; page 526 - page 530; VOL.37, No.4	
JZ	8	S.M.SZE; Physics of Semiconductor Devices; John Wiley & Sons. Inc.; 1985; page 28-29; 2nd ed.	

Examiner Signature	Jeffrey Zweizig	Date Considered	9/26/05
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